

Product Change Notice

Last Update: 2016/10/6

PAPS Announcement:

We have recently received product change notice from manufacturer for the following products. This announcement takes effective immediately. Please review this notice carefully and contact with product manager or your regional PAPS representatives, should you have any question.

Description of the Change

DDR2 DIE change:

1. Samsung 64MX8 35nm Q DIE to 64MX8 25nm N DIE
2. Samsung 128MX8 35nm G DIE to 128MX8 25nm J DIE

Effective Date	Start Date	Last Shipment Date	Cut-in Implementation
2016/10/6	2017/1/1	2016/12/1	2017/1/1

Affected Products:

Part Number	MPN	Product Description
96SD2-512M667NN-TR	TS6QJSJ23002-6S/ TS64MSQ64V6J	512M SO-DDR2-667 200Pin 64MX8
96D2-512M667NN-TRL	TS6QNJ29600-6S	512M DDR2-667 240Pin 64MX8 VLP
96D2-1G667NN-TRL	TS2QNJ29800-6S	1G DDR2-667 240Pin 64MX8 VLP
96SD2-1G800NN-TR1	TS2QSU23003-4S	1G SO-DDR2-800 200Pin 128MX8
96D2-1G800NN-TRL1	TS2QNU29600-5S	1G DDR2-800 240Pin128MX8 VLP
96SD2-2G800NN-TR1	TS5QSU21640-4S	2G SO-DDR2-800 200 Pin 128MX8
96D2-2G800NN-TRL1	TS5QNU29800-5S	2G DDR2-800 240 Pin 128MX8 VLP

Effective Date	Start Date	Last Shipment Date	Cut-in Implementation
2016/10/6	2016/10/6	2016/10/6	2016/10/6

Affected Products:

Part Number	MPN	Product Description
96SD2-1G667NN-AP3	78.02G72.402	1G SO-DDR2-667 200Pin 128MX8
96SD2-2G667NN-AP3	78.A2G72.405	2G SO-DDR2-667 200Pin 128MX8
96SD2-1G800NN-AP3	78.02G86.402	1G SO-DDR2-800 200Pin 128MX8
96SD2-2G800NN-AP2	78.A2G86.405	2G SO-DDR2-800 200Pin 128MX8
96D2-1G800NN-AP3	78.01GAR.405	1G DDR2-800 240Pin 128MX8
96D2-2G800NN-AP	78.A1GAR.404	2G DDR2-800 240Pin 128MX8
96D2-2G800E-AP1	78.A1GAS.403	2G DDR2-800 240Pin ECC 128MX8

*Should you have any question regarding products, please contact PM, Lindsay Chou (lindsay.chou@advantech.com.tw ; 511-7931) or your regional buyers for purchasing information.